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SPECIFICATIONS

PXIe-5644

Reconfigurable 6 GHz Vector Signal Transceiver

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Definitions

Warranted specifications describe the performance of a model under stated operating conditions and are covered by the model warranty.

Characteristics describe values that are relevant to the use of the model under stated operating conditions but are not covered by the model warranty.

- *Typical* specifications describe the expected performance met by a majority of the models.
- 2σ specifications describe the 95th percentile values, in which 95% of the cases are met with a 95% confidence.
- Nominal specifications describe parameters and attributes that may be useful in operation.

Within the specifications, self-calibration °C refers to the recorded device temperature of the last successful self-calibration.

Specifications are Warranted unless otherwise noted.

Conditions

Specifications are valid under the following conditions unless otherwise noted.

- 30 minutes warm-up time.
- Calibration cycle is maintained.
- Chassis fan speed is set to High. In addition, NI recommends using slot blockers and EMC filler panels in empty module slots to minimize temperature drift.
- Calibration IP is used properly during the creation of custom FPGA bitfiles.
- Calibration Interconnect cable remains connected between CAL IN and CAL OUT front panel connectors.
- The cable connecting CAL IN to CAL OUT has not been removed or tampered with.
- Reference Clock source: Internal
- RF IN reference level: 0 dBm
- RF OUT power level: 0 dBm
- LO tuning mode: Fractional
- LO PLL loop bandwidth: Medium
- LO step size: 200 kHz
- LO frequency: 2.4 GHz
- LO source: Internal

Frequency

The following characteristics are common to both RF IN and RF OUT ports.

requency range	65 MHz to 6 GHz
andwidth ¹	80 MHz
uning resolution ²	<1 Hz
O step size	
Fractional mode	Programmable step size, 200 kHz default
Integer mode	4 MHz, 5 MHz, 6 MHz, 12 MHz, 24 MHz
	<u> </u>

¹ Digitally equalized RF input and RF output bandwidth. Bandwidth is restricted to 20 MHz for LO frequencies ≤ 109 MHz and restricted to 40 MHz for LO frequencies between 109 MHz and 375 MHz.

² Tuning resolution combines LO step size capability and frequency shift DSP implemented on the FPGA.

Frequency Settling Time

	Maximum Time (ms)			
Settling Time	Low Loop Bandwidth	Medium Loop Bandwidth ³ (default)	High Loop Bandwidth	
$\leq 1 \times 10^{-6}$ of final frequency	1.1	0.95	0.38	
$\leq 0.1 \times 10^{-6}$ of final frequency	1.2	1.05	0.4	

Table 1. Maximum Frequency Settling Time

The default medium loop bandwidth refers to a setting that adjusts PLL to balance tuning speed and phase noise, and it does not necessarily result in loop bandwidth between low and high.

This specification includes only frequency settling and excludes any residual amplitude settling.

Internal Frequency Reference

Initial adjustment accuracy	$\pm 200 imes 10^{-9}$
Temperature stability	$\pm 1 \times 10^{-6}$, maximum
Aging	$\pm 1 \times 10^{-6}$ per year, maximum
Accuracy	Initial adjustment accuracy $\pm Aging \pm$
	Temperature stability

Frequency Reference Input (REF IN)

Refer to the *REF IN* section.

Frequency Reference/Sample Clock Output (REF OUT)

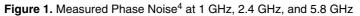
Refer to the *REF OUT* section.

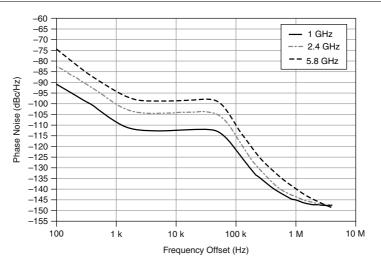
³ Medium loop bandwidth is available only in fractional mode.

Spectral Purity

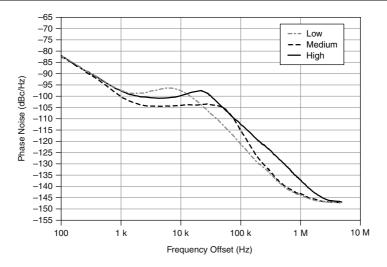
	Phase Noise (dBc/Hz), 20 kHz Offset (Single Sideband)			
Frequency	Low Loop Bandwidth	Medium Loop Bandwidth	High Loop Bandwidth	
<3 GHz	-99	-99	-94	
3 GHz to 4 GHz	-91	-93	-91	
>4 GHz to 6 GHz	-93	-93	-87	

Table 2. Single Sideband Phase Noise





⁴ Conditions: Measured port: LO Out; Reference Clock: internal; medium loop bandwidth.



RF Input

Amplitude Range

Amplitude range	Average noise level to +30 dBm (CW RMS)
RF reference level range/resolution	≥60 dB in 1 dB nominal steps
Amplitude Settling Time	
<0.1 dB of final value ⁶	125 µs, typical
<0.5 dB of final value ⁷ , with LO retuned	300 µs

⁵ Conditions: Measured port: LO Out; Reference Clock: internal.

⁶ Constant LO frequency, constant RF input signal, varying input reference level.

⁷ LO tuning across harmonic filter bands, constant RF input signal, varying input reference level.

Absolute Amplitude Accuracy

Question	15 °C to 35 °C		0 °C to 55 °C	
Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
65 MHz to	_	±0.70	_	±0.75
<375 MHz		$\pm 0.65 (95th)$ percentile, $\approx 2\sigma$)	_	$\pm 0.65 (95th$ percentile, $\approx 2\sigma$)
	±0.34, typical	±0.50, typical	±0.36, typical	±0.55, typical
375 MHz to	_	±0.65		±0.70
<2 GHz		$\pm 0.55 (95th)$ percentile, $\approx 2\sigma$)		± 0.55 (95th percentile, $\approx 2\sigma$)
	±0.17, typical	±0.35, typical	±0.22, typical	±0.40, typical
2 GHz to	_	±0.70		±0.75
<4 GHz		$\pm 0.55 (95th)$ percentile, $\approx 2\sigma$)		$\pm 0.60 (95th$ percentile, $\approx 2\sigma$)
	±0.23, typical	±0.40, typical	±0.26, typical	±0.40, typical
4 GHz to 6 GHz	—	±0.90	_	±0.95
	_	$\pm 0.75 (95th)$ percentile, $\approx 2\sigma$)	_	$\pm 0.80 (95th)$ percentile, $\approx 2\sigma$)
	±0.30, typical	±0.55, typical	±0.33, typical	±0.55, typical

Table 3. VSA Absolute Amplitude Accuracy (dB)

Conditions: Reference level -30 dBm to +30 dBm; measured at 3.75 MHz offset from the configured center frequency; measurement performed after the PXIe-5644 has settled.

For reference levels <-30 dBm, absolute amplitude gain accuracy is ± 0.6 dB, typical for frequencies ≤ 4 GHz, and ± 0.8 dB, typical for frequencies > 4 GHz. Performance depends on signal-to-noise ratio.

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

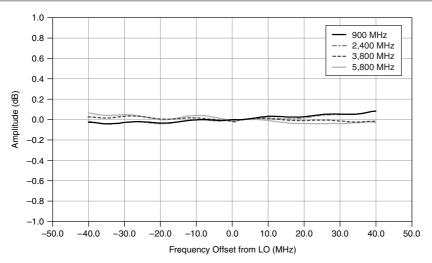
Frequency Response

RF Input Frequency	Bandwidth	Self-Calibration °C ± 5 °C	
≤109 MHz	20 MHz	±1.0, typical	
>109 MHz to 375 MHz	20 MHz	±0.5	
	40 MHz	±1.0, typical	
>375 MHz to 6 GHz	80 MHz	±0.5	

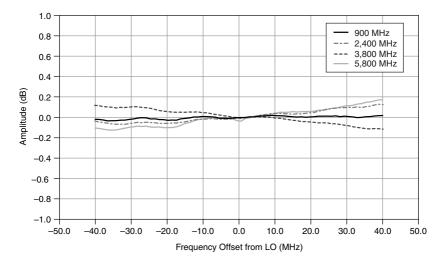
Table 4. VSA Frequency Response (dB) (Amplitude, Equalized)

Conditions: Reference level -30 dBm to +30 dBm. This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.





⁸ Measurement performed after self-calibration.



Average Noise Density

Contor Fraguenov	Average Noise Level		
Center Frequency	-50 dBm Reference Level	-10 dBm Reference Level	
65 MHz to 4 GHz	-159	-145	
	-161, typical	-148, typical	
>4 GHz to 6 GHz	-156	-144	
	-158, typical	-146, typical	

Conditions: Input terminated with a 50 Ω load; 50 averages; RMS average noise level normalized to a 1 Hz noise bandwidth.

The -50 dBm reference level configuration has the inline preamplifier enabled, which represents the high sensitivity operation of the receive path.

Spurious Responses

Nonharmonic Spurs

Table 6.	Nonharmonic	Spurs ((dBc)
14010 01	1 tornia monitorno	opulo	(ab0)

		1 1 1	
Frequency	<100 kHz Offset	≥100 kHz Offset	>1 MHz Offset
65 MHz to 3 GHz	<-55, typical	<-60	<-75
>3 GHz to 6 GHz	<-55, typical	<-55	<-70

Conditions: Reference level \geq -30 dBm. Measured with a single tone, -1 dBr, where dBr is referenced to the configured RF reference level.

LO Residual Power

Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
≤109 MHz	_	-62
	-67, typical	-67, typical
>109 MHz to 375 MHz	_	-58
	-65, typical	-61, typical
>375 MHz to 1 GHz	—	-53
	-58, typical	-56, typical
1 GHz to 3 GHz	_	-52
	-58, typical	-56, typical
3 GHz to 4 GHz	—	-44
	-49, typical	-47, typical

Table 7. VSA LO Residual Power (dBr⁹)

⁹ dBr is relative to the full scale of the configured RF reference level.

Table 7. VSA LO Residual Power (dBr*) (Continued)			
Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C	
4 GHz to 6 GHz	_	-43	

-46, typical

Table 7. VSA LO Residual Power (dBr9) (Continued)

Conditions: Reference levels -30 dBm to +30 dBm; Measured at ADC.

-48, typical

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

For optimal performance, NI recommends running self-calibration when the PXIe-5644 temperature drifts \pm 5 °C from the temperature at the last self-calibration. For temperature changes > \pm 5 °C from self-calibration, LO residual power is -35 dBr.

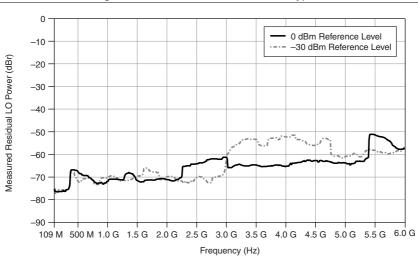


Figure 5. VSA LO Residual Power, ¹⁰ Typical

⁹ dBr is relative to the full scale of the configured RF reference level.

¹⁰ Conditions: VSA frequency range 109 MHz to 6 GHz. Measurement performed after selfcalibration.

Residual Sideband Image

Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
≤109 MHz	_	-40
	-60, typical	-50, typical
>109 MHz to 500 MHz	_	-40
	-50, typical	-45, typical
>500 MHz to 3 GHz	_	-65
	-75, typical	-70, typical
>3 GHz to 5 GHz	_	-55
	-70, typical	-60, typical
>5 GHz to 6 GHz	_	-60
	-70, typical	-65, typical

Table 8. VSA Residual Sideband Image, 80 MHz Bandwidth (dBc)

Conditions: Reference levels -30 dBm to +30 dBm.

This specification describes the maximum residual sideband image within an 80 MHz bandwidth at a given RF center frequency. Bandwidth is restricted to 20 MHz for LO frequencies \leq 109 MHz.

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

For optimal performance, NI recommends running self-calibration when the PXIe-5644 temperature drifts \pm 5 °C from the temperature at the last self-calibration. For temperature changes > \pm 5 °C from self-calibration, residual image suppression is -40 dBc.

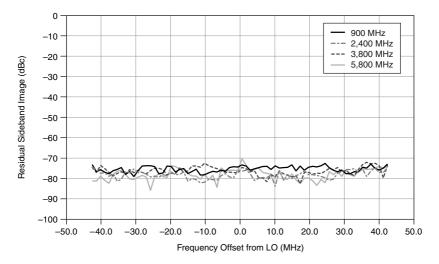
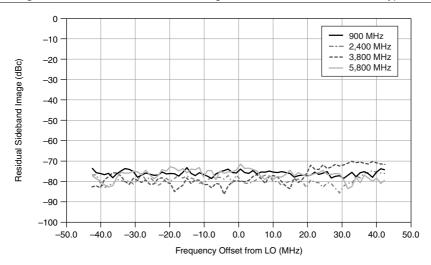


Figure 7. VSA Residual Sideband Image,¹¹ -30 dBm Reference Level, Typical



¹¹ Measurement performed after self-calibration.

Third-Order Input Intermodulation

Frequency Range	IIP ₃ (dBm)	
65 MHz to 1.5 GHz	19	
>1.5 GHz to 6 GHz	20	
Conditions: Two -10 dBm tones. 700 kHz apart at RF IN: reference level: -5 dBm <4 GHz.		

Table 9. Third-Order Input Intercept Point (IIP₃), -5 dBm Reference Level, Typical

Conditions: Two -10 dBm tones, 700 kHz apart at RF IN; reference level: -5 dBm <4 GHz, -2 dBm reference level otherwise; nominal noise floor: -148 dBm/Hz for -5 dBm reference level, -145 dBm/Hz for -2 dBm reference level.

Table 10. Third-Order Input Intercept Point (IIP₃), -20 dBm Reference Level, Typical

IIP ₃ (dBm)
9
11
8
6
4
1

Conditions: Two -25 dBm tones, 700 kHz apart at RF IN; reference level: -20 dBm; nominal noise floor: -157 dBm/Hz.

Second-Order Input Intermodulation

Table 11. Second-Order Input Intercept Point (II)	IP ₂), -2 dBm Reference Level, Typical ¹²

-

Frequency Range	IIP ₂ (dBm)
65 MHz to 1.5 GHz	67
>1.5 GHz to 4 GHz	58
>4 GHz to 6 GHz	52

¹² Conditions: Two -10 dBm tones, 700 kHz apart at RF IN; reference level: -2 dBm; nominal noise floor: -145 dBm/Hz.

Power Range

Output Type	Frequency	Power Range	
CW	<4 GHz	Noise floor to +10 dBm, average power ¹³	Noise floor to +15 dBm, average power, nominal
	≥4 GHz	Noise floor to +7 dBm, average power ¹³	Noise floor to +12 dBm, average power, nominal
Modulated ¹⁴	<4 GHz	Noise floor to +6 dBm, average power	
	≥4 GHz	Noise floor to +3 dBm, average power	_

Output attenuator resolution	2 dB, nominal

```
Digital attenuation resolution<sup>15</sup> 0.1 dB or better
```

Related Information

Refer to the Considering Average Power and Crest Factor topic of the NI RF Vector Signal Transceivers Help for more information about modulated signal power.

Amplitude Settling Time

0.1 dB of final value ¹⁶	50 µs
0.5 dB of final value ¹⁷ , with LO retuned	300 µs

¹³ Higher output is uncalibrated and may be compressed.

¹⁴ Up to 12 dB crest factor, based on 3GPP LTE uplink requirements.

¹⁵ Average output power \geq -100 dBm.

 $^{^{16}}$ Constant LO frequency, varying RF output power range. Power levels ≤ 0 dBm. 175 μs for power levels > 0 dBm.

¹⁷ LO tuning across harmonic filter bands.

Output Power Level Accuracy

	15 °C	to 35 °C	0 °C t	o 55 °C
Center Frequency	Self- Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C	Self- Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
65 MHz to	_	±0.70		±0.90
<109 MHz	_	± 0.55 (95th percentile, $\approx 2\sigma$)		$\pm 0.65 (95th)$ percentile, $\approx 2\sigma$)
	±0.26, typical	±0.40, typical	±0.36, typical	±0.50, typical
109 MHz to		±0.75		±0.90
<270 MHz ¹⁸		$\pm 0.60 (95 \text{th} \text{percentile}; \approx 2\sigma)$		$\pm 0.70 (95th)$ percentile; $\approx 2\sigma$)
	±0.26, typical	±0.45, typical	±0.36, typical	±0.55, typical
270 MHz to		±0.70		±0.90
<375 MHz		± 0.55 (95th percentile, $\approx 2\sigma$)		± 0.65 (95th percentile, $\approx 2\sigma$)
	±0.26, typical	±0.40, typical	±0.36, typical	±0.50, typical
375 MHz to		±0.75		±0.90
<2 GHz	_	± 0.55 (95th percentile, $\approx 2\sigma$)		$\pm 0.65 (95th)$ percentile, $\approx 2\sigma$)
	±0.26, typical	±0.40, typical	±0.36, typical	±0.50, typical
2 GHz to <4 GHz		±0.75		±0.90
		$\pm 0.60 (95th$ percentile, $\approx 2\sigma$)		$\pm 0.70 (95th)$ percentile, $\approx 2\sigma$)
	±0.26, typical	± 0.40 , typical	±0.36, typical	±0.50, typical

Table 13. Output Power Level Accuracy (dB)

¹⁸ Harmonic suppression is reduced in this frequency range. As a result, offset errors may occur depending on whether you are using a true RMS device, such as a power meter.

	15 °C to 35 °C		0 °C to 55 °C	
Center Frequency	Self- Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C	Self- Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
4 GHz to 6 GHz		±1.00		±1.15
		$\pm 0.80 (95th)$ percentile, $\approx 2\sigma$)	_	$\pm 0.90 (95th$ percentile, $\approx 2\sigma$)
	±0.28, typical	±0.40, typical	±0.38, typical	±0.60, typical

Table 13. Output Power Level Accuracy (dB) (Continued)

Conditions: CW average power -70 dBm to +10 dBm.

For power <-70 dBm, highly accurate generation can be achieved using digital attenuation, which relies on DAC linearity.

The absolute amplitude accuracy is measured at 3.75 MHz offset from the configured center frequency. The absolute amplitude accuracy measurements are made after the PXIe-5644 has settled.

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

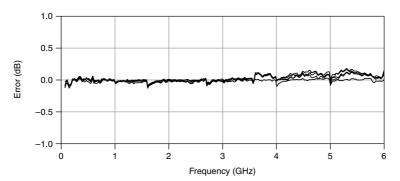


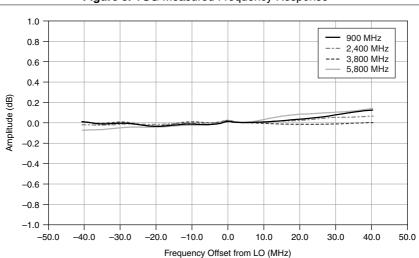
Figure 8. Relative Power Accuracy, -40 dBm to 10 dBm, 10 dB Steps, Typical

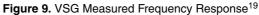
Frequency Response

Output Frequency	Bandwidth	Self-Calibration °C ± 5 °C	
≤109 MHz	20 MHz	±1.0, typical	
>109 MHz to 375 MHz	20 MHz	±0.5	
	40 MHz	±1.0, typical	
>375 MHz to 6 GHz	80 MHz	±0.5	
	1	1	

 Table 14. VSG Frequency Response (dB) (Amplitude, Equalized)

For this specification, frequency refers to the RF output frequency. This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.





¹⁹ Conditions: Output -10 dBm CW tone. Measurement performed after self-calibration.

Output Noise Density

		Power Setting		
Center Frequency	-30 dBm	0 dBm	10 dBm	
65 MHz to 500 MHz		_	-136	
	-168, typical	-150, typical	-140, typical	
>500 MHz to 2.5 GHz	-168, typical	-150	-141	
>2.5 GHz to 3.5GHz	-168, typical	-149	-139	
>3.5 GHz to 6 GHz	-165, typical	-147	-136	

Table 15. Average Output Noise Level (dBm/Hz)

Conditions: Averages: 200 sweeps; baseband signal attenuation: -40 dB; noise measurement frequency offset: 4 MHz relative to output tone frequency.

Spurious Responses

Harmonics

Fundamental Frequency	23 °C ± 5 °C	0 °C to 55 °C
65 MHz to 3.5 GHz	-27	-24.8
	-29.5, typical	-27.2, typical
>3.5 GHz to 4.5 GHz	-26.3	-24
	-28.9, typical	-26.6, typical
>4.5 GHz to 6 GHz	-28.9	-26.6
	-33.3, typical	-31, typical

Table 16. Second Harmonic Level (dBc)

Conditions: Measured using 1 MHz baseband signal -1 dBFS; fundamental signal measured at +6 dBm CW; second harmonic levels nominally <-30 dBc for fundamental output levels of \leq 5 dBm.

E

Note Higher order harmonic suppression is degraded in the range of 109 MHz to 270 MHz, and third harmonic performance is shown in the following figure. For frequencies outside the range of 109 MHz to 270 MHz, higher order harmonic

distortion is equal to or better than the second harmonic level as specified in the previous table.

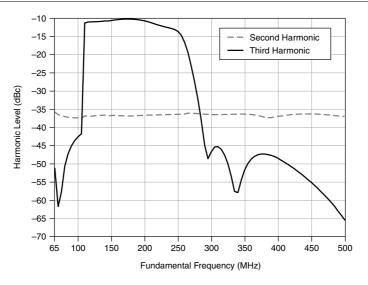


Figure 10. Harmonic Level,²⁰ 65 MHz to 500 MHz, Measured

Nonharmonic Spurs

Table 17	. Nonharmonic	Spurs	(dBc)
14010 11		opulo	(ab0)

Frequency	<100 kHz Offset	≥100 kHz Offset	>1 MHz Offset
65 MHz to 3 GHz	<-55, typical	<-62	<-75
>3 GHz to 6 GHz	<-55, typical	<-57	<-70

Conditions: Output full scale level \geq -30 dBm. Measured with a single tone at -1 dBFS.

Third-Order Output Intermodulation

Table 18. Third-Order Output Intermodulatio	n Distortion (IMD ₃) (dBc), 0 dBm Tones
---	---

Fundamental Frequency	Baseband DAC: -2 dBFS	Baseband DAC: -6 dBFS
65 MHz to 1 GHz	-55, typical	-60, typical
>1 GHz to 3 GHz	-53, typical	-53, typical

²⁰ Measured using 1 MHz baseband signal -1 dBFS; fundamental signal measured at +6 dBm CW.

 Table 18. Third-Order Output Intermodulation Distortion (IMD₃) (dBc), 0 dBm

 Tones (Continued)

Fundamental Frequency	Baseband DAC: -2 dBFS	Baseband DAC: -6 dBFS	
>3 GHz to 5 GHz	-49, typical	-50, typical	
>5 GHz to 6 GHz	-44, typical	-45, typical	
Conditions: Two 0 dBm tones, 500 kHz apart at RF OUT.			
RF gain applied to achieve the desired output power per tone.			

Table 19. Third-Order Output Intermodulation Distortion (IMD₃) (dBc), -6 dBm Tones

Fundamental Frequency	Baseband DAC: -2 dBFS	Baseband DAC: -6 dBFS
65 MHz to 1.5 GHz	-50	-59
	-54, typical	-62, typical
>1.5 GHz to 3.5 GHz	-54	-59
	-57, typical	-62, typical
>3.5 GHz to 5 GHz	-50	-55
	-53, typical	-58, typical
>5 GHz to 6 GHz	-47	-51
	-50, typical	-54, typical
Conditions: Two -6 dBm tones	s, 500 kHz apart at RF OUT.	1

RF gain applied to achieve the desired output power per tone.

Table 20. Third-Order Output Intermodulation	Distortion (IMD ₃) (dBc), -36 dBm Tones
--	---

Fundamental Frequency	Baseband DAC: -2 dBFS	Baseband DAC: -6 dBFS
65 MHz to 200 MHz	-52	-57
	-54, typical	-60, typical

 Table 20. Third-Order Output Intermodulation Distortion (IMD₃) (dBc), -36 dBm

 Tones (Continued)

Fundamental Frequency	Baseband DAC: -2 dBFS	Baseband DAC: -6 dBFS
>200 MHz to 6 GHz	-52	-55
	-54, typical	-58, typical
Conditions: Two -36 dBm tones, 500 kHz apart at RF OUT.		
RF gain applied to achieve the desired output power per tone.		

LO Residual Power

Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
≤109 MHz	_	-50
	-57, typical	-55, typical
>109 MHz to 375 MHz	_	-42
	-47, typical	-45, typical
>375 MHz to 1.6 GHz	_	-55
	-62, typical	-60, typical
1.6 GHz to 2 GHz	_	-54
	-60, typical	-58, typical
2 GHz to 3 GHz	_	-47
	-53, typical	-51, typical
3 GHz to 4 GHz	_	-52
	-57, typical	-55, typical
4 GHz to 5 GHz	_	-51
	-60, typical	-56, typical

Table 21. VSG LO Residual Power (dBc)

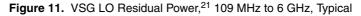
Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
5 GHz to 6 GHz	_	-47
	-56, typical	-52, typical

Table 21. VSG LO Residual Power (dBc) (Continued)

Conditions: Configured power levels -50 dBm to +10 dBm.

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

For optimal performance, NI recommends running self-calibration when the PXIe-5644 temperature drifts \pm 5 °C from the temperature at the last self-calibration. For temperature changes $\geq \pm$ 5 °C from self-calibration, LO residual power is -40 dBc.



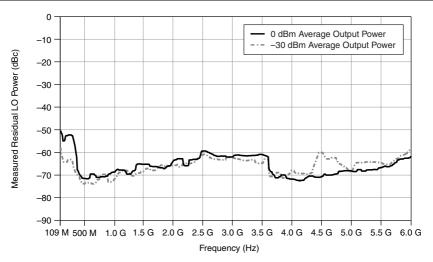


Table 22. VSG LO Resid	ual Power (dBc), Low Power
------------------------	----------------------------

Center Frequency	Self-Calibration °C ± 5 °C
≤109 MHz	_
	-49, typical

²¹ Measurement performed after self-calibration.

Center Frequency	Self-Calibration °C ± 5 °C
>109 MHz to 375 MHz	-45
	-50, typical
>375 MHz to 2 GHz	-55
	-60, typical
>2 GHz to 3 GHz	-50
	-53, typical
>3 GHz to 4 GHz	-55
	-58, typical
>4 GHz to 5 GHz	_
	-40, typical
>5 GHz to 6 GHz	-43
	-45, typical

Table 22. VSG LO Residual Power (dBc), Low Power (Continued)

Conditions: Configured power levels < -50 dBm to -70 dBm.

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

For optimal performance, NI recommends running self-calibration when the PXIe-5644 temperature drifts \pm 5 °C from the temperature at the last self-calibration. For temperature changes > \pm 5 °C from self-calibration, LO residual power is -40 dBc.

Residual Sideband Image

Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
≤109 MHz		-40
	-55, typical	-45, typical
>109 MHz to 375 MHz		
	-45, typical	-40, typical

Table 23. VSG Residual Sideband Image (dBc), 80 MHz Bandwidth

Center Frequency	Self-Calibration °C ± 1 °C	Self-Calibration °C ± 5 °C
>375 MHz to 2 GHz	_	-60
	-70, typical	-65, typical
>2 GHz to 4 GHz	_	-50
	-65, typical	-55, typical
>4 GHz to 6 GHz	_	-40
	-70, typical	-50, typical

Table 23. VSG Residual Sideband Image (dBc), 80 MHz Bandwidth (Continued)

Conditions: Configured power levels -50 dBm to +10 dBm.

This specification describes the maximum residual sideband image within an 80 MHz bandwidth at a given RF center frequency. Bandwidth is restricted to 20 MHz for LO frequencies \leq 109 MHz.

This specification is valid only when the module is operating within the specified ambient temperature range and within the specified range from the last self-calibration temperature, as measured with the onboard temperature sensors.

For optimal performance, NI recommends running self-calibration when the PXIe-5644 temperature drifts \pm 5 °C from the temperature at the last self-calibration. For temperature changes > \pm 5 °C from self-calibration, residual image suppression is -40 dBc.

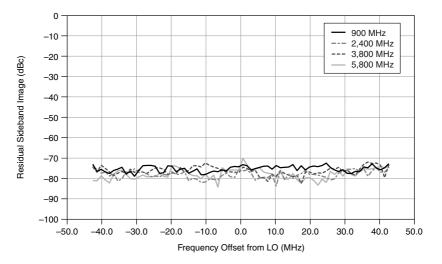
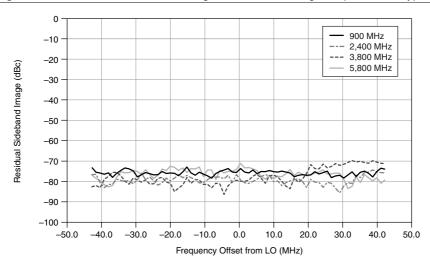


Figure 13. VSG Residual Sideband Image,²² -30 dBm Average Output Power, Typical



²² Measurement performed after self-calibration.

VSA EVM

20 MHz bandwidth 64-QAM EVM²³ 375 MHz to 6 GHz

> 0 -5 0 Hz Offset From LO 10 MHz Offset From LO -10 - 20 MHz Offset From LO -15 · -20 EVM RMS (dB) -25 -30 -35 -40 -45 -50 · -55 -60 -3.0 G 3.5 G 4.0 G 4.5 G 375.0 M 1.0 G 1.5 G 2.0 G 2.5 G 5.0 G 5.5 G 6.0 G Center Frequency (Hz)



-40 dB, typical

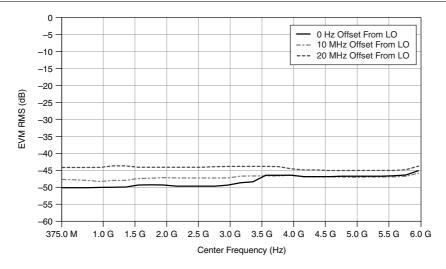
VSG EVM

20 MHz bandwidth 64-QAM EVM²⁵ 375 MHz to 6 GHz -40 dB, typical

²³ Conditions: EVM signal: 20 MHz bandwidth; 64 QAM signal. Pulse-shape filtering: root-raised-cosine, alpha=0.25; PXIe-5644 reference level: -10 dBm; Reference Clock source: internal; record length: 300 μs. Generator: PXIe-5673; power (average): -14 dBm; Reference Clock source: internal.

²⁴ Conditions: 20 MHz bandwidth, 64 QAM; centered at LO frequency or offset digitally as listed.

²⁵ Conditions: EVM signal: 20 MHz bandwidth; 64 QAM signal. Pulse-shape filtering: root-raised cosine, alpha=0.25; PXIe-5644 peak output power: -10 dBm; Reference Clock source: internal. Measurement instrument: PXIe-5665; reference level: -10 dBm; Reference Clock source: internal; record length: 300 μs.



Application-Specific Modulation Quality

Typical performance assumes the PXIe-5644 is operating within \pm 5 °C of the previous selfcalibration temperature, and that the ambient temperature is 0 °C to 55 °C.

WLAN 802.11ac

OFDM²⁷

-45 EVM (rms) dB, typical

WLAN 802.11n

	1 7 1	7. . .
Frequency	20 MHz Bandwidth	40 MHz Bandwidth
2,412 MHz	-50	-50
5,000 MHz	-48	-46
Conditions: RF OUT loopback to RF IN; average power: -10 dBm; reference level: auto- leveled based on real-time average power measurement; 20 packets; 3/4 coding rate; 64 QAM.		

Table 24. 802.11n OFDM EVM (rms) (dB), Typical

²⁶ Conditions: 20 MHz bandwidth, 64 QAM; centered at LO frequency or offset digitally as listed.

²⁷ Conditions: RF OUT loopback to RF IN; 5,800 MHz; 80 MHz bandwidth; average power: -30 dBm to -5 dBm; 20 packets; 16 OFDM data symbols; MCS=9; 256 QAM.

WLAN 802.11a/g/j/p

Frequency	20 MHz Bandwidth
2,412 MHz	-53
5,000 MHz	-50
	1

Conditions: RF OUT loopback to RF IN; average power: -10 dBm; reference level: autoleveled based on real-time average power measurement; 20 packets; 3/4 coding rate; 64 QAM.

WLAN 802.11g

Table 26. 802.11g DSSS-OFDM EVM (rms) (dB), Typical

Frequency	20 MHz Bandwidth
2,412 MHz	-53
5,000 MHz	-50

Conditions: RF OUT loopback to RF IN; average power: -10 dBm; reference level: autoleveled based on real-time average power measurement; 20 packets; 3/4 coding rate; 64 QAM.

WLAN 802.11b/g

DSSS²⁸

-48 EVM (rms) dB, typical

LTE

Frequency	5 MHz Bandwidth	10 MHz Bandwidth	20 MHz Bandwidth
700 MHz	-56	-56	-54
900 MHz	-55	-55	-53
1,430 MHz	-54	-54	-53

Table 27. SC-FDMA²⁹ (Uplink FDD) EVM (rms) (dB), Typical

²⁸ Conditions: RF OUT loopback to RF IN; 2,412 MHz; 20 MHz bandwidth; average power -10 dBm; reference level: auto-leveled based on real-time average power measurement; averages: 10; pulse-shaping filter: Gaussian reference; CCK 11 Mbps.

²⁹ Single channel uplink only.

Frequency	5 MHz Bandwidth	10 MHz Bandwidth	20 MHz Bandwidth
1,750 MHz	-51	-50	-50
1,900 MHz	-51	-50	-50
2,500 MHz	-50	-49	-49

Table 27. SC-FDMA²⁹ (Uplink FDD) EVM (rms) (dB), Typical (Continued)

WCDMA

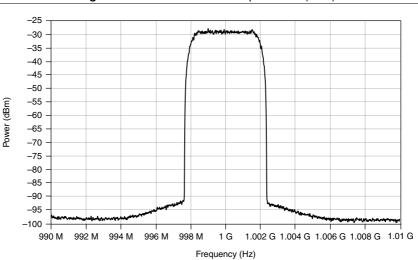


Figure 16. WCDMA Measured Spectrum³⁰ (ACP)

Baseband Characteristics

Resolution	16 bits
Sample rate ³¹	120 MS/s
I/Q data rate ³²	1.84 kS/s to 120 MS/s

²⁹ Single channel uplink only.

³⁰ Conditions: DL Test Model 1 (64DPCH); RF output level: -10 dBm average; RF OUT loopback to RF IN; measured results better than -66 dB.

³¹ ADCs are dual-channel components with each channel assigned to I and Q, respectively.

 $^{^{32}}$ I/Q data rates lower than 120 MS/s are achieved using fractional decimation.

Digital-to-analog converters (DACs)

Resolution	16 bits
Sample rate ³³	120 MS/s
I/Q data rate ³⁴	1.84 kS/s to 120 MS/s

Onboard FPGA

FPGA	Xilinx Virtex-6 LX195T
LUTs	124,800
Flip-flops	249,600
DSP48 slices	640
Embedded block RAM	12,384 kbits
Data transfers	DMA, interrupts, programmed I/O
Number of DMA channels	16

Onboard DRAM

Memory size	2 banks, 256 MB per bank
Theoretical maximum data rate	2.1 GB/s per bank

Onboard SRAM

Memory size	2 MB
Maximum data rate (read)	40 MB/s
Maximum data rate (write)	36 MB/s

Front Panel I/O

RF IN

Connector	SMA (female)
Input impedance	50 Ω , nominal, AC coupled
Maximum DC input voltage without damage	8 V
Absolute maximum input power ³⁵	+33 dBm (CW RMS)

³³ DACs are dual-channel components with each channel assigned to I and Q, respectively. DAC sample rate is internally interpolated to 960 MS/s, automatically configured.

³⁴ I/Q data rates lower than 120 MS/s are achieved using fractional interpolation.

³⁵ For modulated signals, peak instantaneous power not to exceed +36 dBm.

Input Return Loss (Voltage Standing Wave Ratio (VSWR))

Frequency	Typical	
$109 \text{ MHz} \leq f < 2.4 \text{ GHz}$	15.5 (1.40:1)	
$2.4 \text{ GHz} \le f < 4 \text{ GHz}$	12.7 (1.60:1)	
$4 \text{ GHz} \leq f \leq 6 \text{ GHz}$	11.0 (1.78:1)	
Return loss for frequencies <109 MHz is typically better than 14 dB (VSWR <1.5:1).		

Table 28. Input Return Loss (dB) (VSWR)

RF OUT

Connector	SMA (female)
Output impedance	50 Ω , nominal, AC coupled
Absolute maximum reverse power ³⁶	
<4 GHz	+33 dBm (CW RMS)
≥4 GHz	+30 dBm (CW RMS)

Output Return Loss (VSWR)

Frequency Typical	
$109 \text{ MHz} \le f < 2 \text{ GHz}$	19.0 (1.25:1)
$2 \text{ GHz} \leq f < 5 \text{ GHz}$	14.0 (1.50:1)
$5 \text{ GHz} \leq f \leq 6 \text{ GHz}$	11.0 (1.78:1)

Return loss for frequencies < 109 MHz is typically better than 20 dB (VSWR < 1.22:1).

CAL IN, CAL OUT

Connector	SMA (female)
Impedance	50 Ω, nominal



Caution Do not disconnect the cable that connects CAL IN to CAL OUT. Removing the cable from or tampering with the CAL IN or CAL OUT front panel connectors voids the product calibration and specifications are no longer warranted.

³⁶ For modulated signals, peak instantaneous power not to exceed corresponding peak power of specified CW.

LO OUT (RF IN 0 and RF OUT 0)

Connectors	SMA (female)
Frequency range ³⁷	65 MHz to 6 GHz
Power	
LO OUT (RF IN 0) 65 MHz to 6 GHz	0 dBm ±2 dB, typical
LO OUT (RF OUT 0)	
65 MHz to 3.6 GHz	0 dBm ±2 dB, typical
\geq 3.6 GHz to 6 GHz	3 dBm ±2 dB, typical
Output power resolution	0.25 dB, nominal
Output impedance	50 Ω , nominal, AC coupled
Output return loss	>11.0 dB (VSWR <1.8:1), typical
Output isolation (state: disabled)	
<2.5 GHz tuned LO	-45 dBc, nominal
	,
≥2.5 GHz tuned LO	-35 dBc, nominal
≥2.5 GHz tuned LO	-35 dBc, nominal
	-35 dBc, nominal
LO IN (RF IN 0 and RF O	-35 dBc, nominal
LO IN (RF IN 0 and RF O	-35 dBc, nominal UT 0) SMA (female)
LO IN (RF IN 0 and RF O Connectors Frequency range ³⁸	-35 dBc, nominal UT 0) SMA (female)
LO IN (RF IN 0 and RF O Connectors Frequency range ³⁸ Expected input power	-35 dBc, nominal UT 0) SMA (female) 65 MHz to 6 GHz
LO IN (RF IN 0 and RF O Connectors Frequency range ³⁸ Expected input power LO IN (RF IN 0) 65 MHz to 6 GHz	-35 dBc, nominal UT 0) SMA (female) 65 MHz to 6 GHz
LO IN (RF IN 0 and RF O Connectors Frequency range ³⁸ Expected input power LO IN (RF IN 0) 65 MHz to 6 GHz LO IN (RF OUT 0)	-35 dBc, nominal UT 0) SMA (female) 65 MHz to 6 GHz 0 dBm ±3 dB, nominal
LO IN (RF IN 0 and RF O Connectors Frequency range ³⁸ Expected input power LO IN (RF IN 0) 65 MHz to 6 GHz LO IN (RF OUT 0) 65 MHz to 3.6 GHz	-35 dBc, nominal UT 0) SMA (female) 65 MHz to 6 GHz 0 dBm ±3 dB, nominal 0 dBm ±3 dB, nominal
LO IN (RF IN 0 and RF O Connectors Frequency range ³⁸ Expected input power LO IN (RF IN 0) 65 MHz to 6 GHz LO IN (RF OUT 0) 65 MHz to 3.6 GHz ≥3.6 GHz to 6 GHz	-35 dBc, nominal UT 0) SMA (female) 65 MHz to 6 GHz 0 dBm ±3 dB, nominal 0 dBm ±1 dB, nominal 3 dBm ±1 dB, nominal
LO IN (RF IN 0 and RF 0) Connectors Frequency range ³⁸ Expected input power LO IN (RF IN 0) 65 MHz to 6 GHz LO IN (RF OUT 0) 65 MHz to 3.6 GHz \geq 3.6 GHz to 6 GHz Input impedance	-35 dBc, nominal UT 0) SMA (female) 65 MHz to 6 GHz 0 dBm ±3 dB, nominal 0 dBm ±1 dB, nominal 3 dBm ±1 dB, nominal 50 Ω, nominal, AC coupled

³⁷ When tuning to 65 MHz to 375 MHz using the RF IN channel, the exported LO is twice the RF frequency requested.

³⁸ When tuning to 65 MHz to 375 MHz using the RF IN channel, the exported LO is twice the RF frequency requested.

REF IN

Connector	SMA (female)	
Frequency	10 MHz	
Tolerance ³⁹	$\pm 10 imes 10^{-6}$	
Amplitude		
Square	0.7 V_{pk-pk} to 5.0 V_{pk-pk} into 50 Ω , typical	
Sine ⁴⁰	1.4 V_{pk-pk} to 5.0 V_{pk-pk} into 50 Ω , typical	
Input impedance	50 Ω, nominal	
Coupling	AC	

REF OUT

Connector	SMA (female)	
Frequency		
Reference Clock ⁴¹	10 MHz, nominal	
Sample Clock	120 MHz, nominal	
Amplitude	1.65 Vpk-pk into 50 Ω, nominal	
Output impedance	50 Ω , nominal	
Coupling	AC	

PFI 0

SMA (female)	
-0.5 V to 5.5 V	
0.8 V	
2.0 V	
0.2 V with 100 µA load	
2.9 V with 100 µA load	
10 kΩ, nominal	
50 Ω , nominal	

³⁹ *Frequency Accuracy = Tolerance × Reference Frequency*

 $^{^{40}\,}$ 1 V_{rms} to 3.5 $V_{rms},$ typical. Jitter performance improves with increased slew rate of input signal.

⁴¹ Refer to the *Internal Frequency Reference* for accuracy.

⁴² Voltage levels are guaranteed by design through the digital buffer specifications.

24 mA

Minimum required direction change latency⁴³

48 ns + 1 clock cycle

DIGITAL I/O

Connector

VHDCI

Table 30. DIGITAL I/O Signal Characteristics

Signal	Direction	Port Width
DIO <2320>	Bidirectional, per port	4
DIO <1916>	Bidirectional, per port	4
DIO <1512>	Bidirectional, per port	4
DIO <118>	Bidirectional, per port	4
DIO <74>	Bidirectional, per port	4
DIO <30>	Bidirectional, per port	4
PFI 1	Bidirectional	1
PFI 2	Bidirectional	1
Clock In	Input	1
Clock Out	Output	1

Voltage levels44

Absolute maximum input range	-0.5 V to 4.5 V
V _{IL}	0.8 V
V _{IH}	2.0 V
V _{OL}	0.2 V with 100 µA load
V _{OH}	2.9 V with 100 µA load
input impedance	
DIO <230>, CLK IN 10 kΩ, nominal	
PFI 1, PFI 2	100 k Ω pull up, nominal

⁴³ Clock cycle refers to the FPGA clock domain used for direction control.

⁴⁴ Voltage levels are guaranteed by design through the digital buffer specifications.

Output impedance	50 Ω , nominal
Maximum DC drive strength	12 mA
Minimum required direction change latency ⁴⁵	48 ns + 1 clock cycle
Maximum toggle rate	125 MHz, typical

Figure 17. DIGITAL I/O VHDCI Connector

NC	1	35	
GND	2	36	GND
NC	3	37	NC
GND	4	38	GND
NC	5	39	NC
GND	6	40	GND
NC	7	41	NC
RESERVED	8	42	GND
DIO 23	9	43	DIO 22
GND	10	44	GND
DIO 21	11	45	DIO 20
GND	12	46	GND
DIO 19	13	47	DIO 18
GND	14	48	GND
DIO 17	15	49	DIO 16
GND	16	50	GND
DIO 15	17	51	DIO 14
GND	18	52	RESERVED
DIO 13	19	53	DIO 12
GND	20	54	GND
DIO 11	21	55	DIO 10
GND	22	56	GND
DIO 9	23	57	DIO 8
GND	24	58	GND
DIO 7	25	59	DIO 6
PFI 1	26	60	RESERVED
DIO 5	27	61	DIO 4
GND	28	62	GND
DIO 3	29	63	DIO 2
NC	30	64	PFI 2
DIO 1	31	65	DIO 0
GND	32	66	GND
CLK OUT	33	67	CLK IN
GND	34	68	GND
l		/	
	\smile	/	

⁴⁵ Clock cycle refers to the FPGA clock domain used for direction control.

Power Requirements

Voltage (V _{DC})	Typical Current (A)	Maximum Current (A)
+3.3	4.9	5.3
+12	3.3	4.2
Power is 56 W, typical. Consumption is from both PXI Express backplane power connectors.		

Table 31. Power Requirements

Calibration

Interval

1 year

Note For the two-year calibration interval, add 0.2 dB to one-year specifications for *Absolute Amplitude Accuracy*, RF input *Frequency Response*, *Output Power Level Accuracy*, and RF output *Frequency Response*.

Physical Characteristics

PXIe-5644 module	3U, three slot, PXI Express module $6.1 \text{ cm} \times 12.9 \text{ cm} \times 21.1 \text{ cm}$
	$(2.4 \text{ in } \times 5.6 \text{ in } \times 8.3 \text{ in})$
Weight	1,360 g (48.0 oz)

Environment

Maximum altitude	2,000 m (800 mbar) (at 25 °C ambient temperature)
Pollution Degree	2

Indoor use only.

Operating Environment

Ambient temperature range	0 °C to 55 °C (Tested in accordance with IEC 60068-2-1 and IEC 60068-2-2. Meets MIL-PRF-28800F Class 3 low temperature limit and MIL-PRF-28800F Class 2 high temperature limit.)
Relative humidity range	10% to 90%, noncondensing (Tested in accordance with IEC 60068-2-56.)
Storage Environment	
Ambient temperature range	-40 °C to 71 °C (Tested in accordance with IEC 60068-2-1 and IEC 60068-2-2. Meets MIL-PRF-28800F Class 3 limits.)
Relative humidity range	5% to 95%, noncondensing (Tested in accordance with IEC 60068-2-56.)

Shock and Vibration

Operating shock	30 g peak, half-sine, 11 ms pulse (Tested in accordance with IEC 60068-2-27. Meets MIL-PRF-28800F Class 2 limits.)
Random vibration	
Operating	5 Hz to 500 Hz, 0.3 g_{rms} (Tested in accordance with IEC 60068-2-64.)
Nonoperating	5 Hz to 500 Hz, 2.4 g_{rms} (Tested in accordance with IEC 60068-2-64. Test profile exceeds the requirements of MIL-PRF-28800F, Class 3.)

Compliance and Certifications

Safety

This product is designed to meet the requirements of the following electrical equipment safety standards for measurement, control, and laboratory use:

- IEC 61010-1, EN 61010-1
- UL 61010-1, CSA C22.2 No. 61010-1



Note For UL and other safety certifications, refer to the product label or the *Online Product Certification* section.

Electromagnetic Compatibility

This product meets the requirements of the following EMC standards for electrical equipment for measurement, control, and laboratory use:

- EN 61326-1 (IEC 61326-1): Class A emissions; Basic immunity
- EN 55011 (CISPR 11): Group 1, Class A emissions
- EN 55022 (CISPR 22): Class A emissions
- EN 55024 (CISPR 24): Immunity
- AS/NZS CISPR 11: Group 1, Class A emissions
- AS/NZS CISPR 22: Class A emissions
- FCC 47 CFR Part 15B: Class A emissions
- ICES-001: Class A emissions



Note In the United States (per FCC 47 CFR), Class A equipment is intended for use in commercial, light-industrial, and heavy-industrial locations. In Europe, Canada, Australia, and New Zealand (per CISPR 11), Class A equipment is intended for use only in heavy-industrial locations.



Note Group 1 equipment (per CISPR 11) is any industrial, scientific, or medical equipment that does not intentionally generate radio frequency energy for the treatment of material or inspection/analysis purposes.



Note For EMC declarations, certifications, and additional information, refer to the *Online Product Certification* section.

CE Compliance $C \in$

This product meets the essential requirements of applicable European Directives, as follows:

- 2014/35/EU; Low-Voltage Directive (safety)
- 2014/30/EU; Electromagnetic Compatibility Directive (EMC)

Online Product Certification

Refer to the product Declaration of Conformity (DoC) for additional regulatory compliance information. To obtain product certifications and the DoC for this product, visit *ni.com/ certification*, search by model number or product line, and click the appropriate link in the Certification column.

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